# UNISONIC TECHNOLOGIES CO., LTD

# BCP68

## NPN SILICON TRANSISTOR

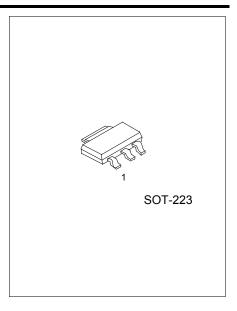
# **NPN MEDIUM POWER TRANSISTOR**

#### **FEATURES**

- \* High current (max. 1 A)
- \* Low voltage (max. 20 V).
- \* Complementary to UTC BCP69

#### **APPLICATIONS**

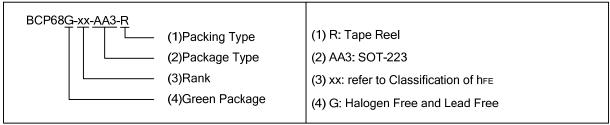
\* General purpose switching and amplification under high current conditions.



#### **ORDERING INFORMATION**

Ordering Number	Doolsono	Pin	Assignn	Dookina	
Ordering Number	Package	1	2	3	Packing
BCP68G-xx-AA3-R	SOT-223	В	С	Е	Tape Reel

Note: Pin Assignment: B: Base C: Collector E: Emitter



## **MARKING**



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### ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage (Oper	n Emitter)	$V_{CBO}$	32	V
Collector-Emitter Voltage (Op	en Base)	$V_{CEO}$	20	V
Emitter-Base Voltage (Open	Collector)	$V_{EBO}$	5	V
Collector Current	DC	I <sub>C</sub>	1	Α
	Peak	I <sub>CM</sub>	2	Α
Peak Base Current		I <sub>BM</sub>	200	mA
Total Power Dissipation (T <sub>A</sub> ≤	25°C)	$P_D$	1.35	W
Junction Temperature		TJ	150	$^{\circ}\mathbb{C}$
Operating Temperature		T <sub>OPR</sub>	-45 ~ +150	$^{\circ}\!\mathbb{C}$
Storage Temperature		T <sub>STG</sub>	-65 ~ +150	$^{\circ}\!\mathbb{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction To Ambient	$\theta_{JA}$	91	°C/W

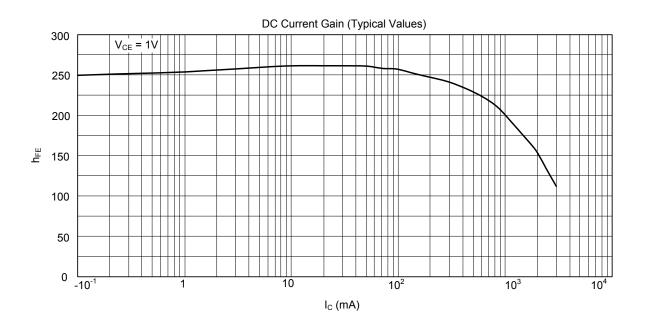
# ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> = 1A, I <sub>B</sub> =100mA			500	mV
Page Emitter Voltage	$V_{BE}$	$I_C = 5mA$ , $V_{CE} = 10V$		620		mV
Base-Emitter Voltage		$I_C = 1A$ , $V_{CE} = 1V$			1	V
Callastar Cut off Current	I <sub>CBO</sub>	$I_E = 0, V_{CB} = 25V$			100	nA
Collector Cut-off Current		I <sub>E</sub> = 0, V <sub>CB</sub> = 25V, T <sub>J</sub> = 150°C			10	μΑ
Emitter Cut-off Current	I <sub>EBO</sub>	$I_{C} = 0, V_{EB} = 5V$			100	nA
DC Current Gain		$I_C = 5mA$ , $V_{CE} = 10V$	50			
		$I_C = 500 \text{mA}, V_{CE} = 1 \text{V}$	85		375	
		$I_C = 1A$ , $V_{CE} = 1V$	60			
Collector Capacitance	C <sub>C</sub>	$I_E = I_e = 0$ , $V_{CB} = 5V$ , $f = 1MHz$		48		pF
Transition Frequency	f <sub>T</sub>	$I_C = -10$ mA, $V_{CE} = -5$ V, $f = 100$ MHz	40			MHz
DC Current Gain Ratio of the	h <sub>FE1</sub>	= 0.50  \/   = 1\/			16	
Complementary Pairs	h <sub>FE2</sub>	I <sub>C</sub>   = 0.5A,  V <sub>CE</sub>   = 1V			1.6	

# CLASSIFICATION OF h<sub>FE</sub>

RANK	16	25
RANGE	100~250	160~375

#### **■ TYPICAL CHARACTERISTIC**



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